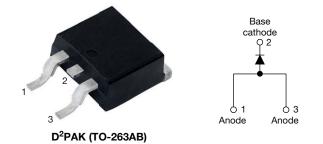
Vishay Semiconductors

High Voltage Surface Mount Input Rectifier Diode, 25 A



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PRIMARY CHARACTERISTICS					
I _{F(AV)} 25 A					
V _R	800 V, 1000 V, 1200 V				
V _F at I _F	1.14 V				
I _{FSM}	300 A				
T _j max.	150 °C				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-25ETS..S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS						
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	20	23	А			

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Sinusoidal waveform	25	A				
V _{RRM}		800 to 1200	V				
I _{FSM}		300	A				
V _F	10 A, T _J = 25 °C	1.0	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-25ETS08S-M3	800	900					
VS-25ETS10S-M3	1000	1100	1				
VS-25ETS12S-M3	1200	1300					

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	$T_C = 106 \ ^{\circ}C$, 180° conduction half sine wave	25			
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated V _{RRM} applied	250	А		
	IFSM	10 ms sine pulse, no voltage reapplied	300			
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s		
Maximum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	442	A-5		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s		

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1



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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS VALUES			UNITS		
Maximum forward voltage drop	V _{FM}	25 A, T _J = 25 °C		1.14	V		
Forward slope resistance	r _t	T - 150 °C	9.62	mΩ			
Threshold voltage	V _{F(TO)}	1J = 150 C	T _J = 150 °C				
Maximum reverse leakage current	1	T _J = 25 °C	$V_{B} = Rated V_{BBM}$	0.1	m۸		
Maximum reverse leakage current	I _{RM}	T _J = 150 °C	VR = haleu VRRM	1.0	mA		

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range)	T _J , T _{Stg}		-40 to +150	°C	
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.9		
Maximum thermal resistance, junction to ambient		R _{thJA}		62	°C/W	
Typical thermal resistance, case to heatsink			Mounting surface, smooth, and greased	0.5		
Approximate weight				2	g	
Approximate weight				0.07	oz.	
Mounting torque	minimum			6 (5)	kgf ⋅ cm	
Mounting torque	Mounting torque maximum			12 (10)	(lbf ⋅ in)	
Marking device				25ET	S08S	
			Case style D ² PAK (TO-263AB)	25ETS10S		
				25ET	S12S	

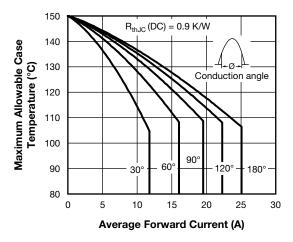


Fig. 1 - Current Rating Characteristics

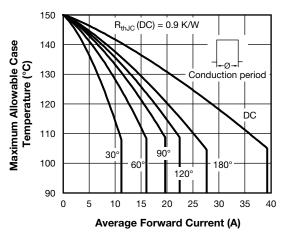
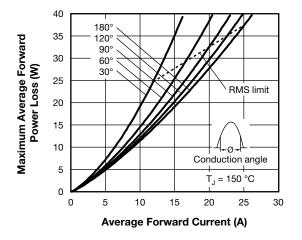


Fig. 2 - Current Rating Characteristics

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Fig. 3 - Forward Power Loss Characteristics

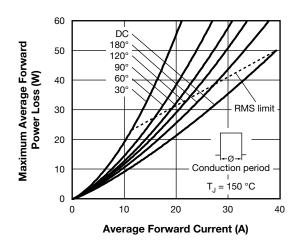


Fig. 4 - Forward Power Loss Characteristics

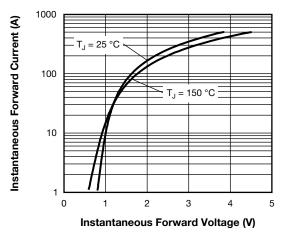
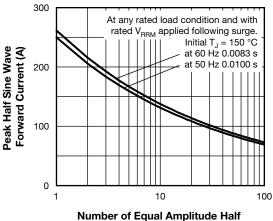


Fig. 7 - Forward Voltage Drop Characteristics



Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

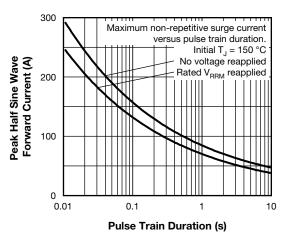
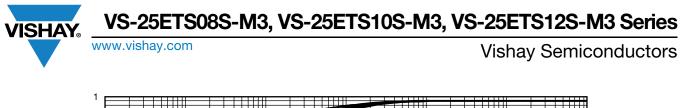


Fig. 6 - Maximum Non-Repetitive Surge Current

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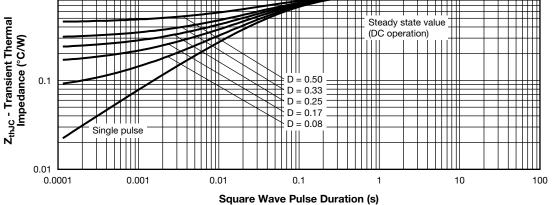


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	25	Е	т	S	12	S	TRL	-M3
	1	2	3	4	5	6	7	8	9
	1 - 2 - 3 - 4 -	Cur Circ E Pac	rrent rati cuit conf = single kage:	niconduo ng (25 = iguration e .K (TO-2	= 25 A) n	oduct			
	5 - 6 - 7 - 8 - 9 -	S Voli S = • No • TF • TF	tage coo surface one = tu RL = tap RR = tap	lard reco de x 100 mounta	i = V _{RRM} ible eel (left o eel (righ	orientec	ed)	08 = 8 10 = 1 12 = 1	000 V 200 V

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ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-25ETS08S-M3	50	1000	Antistatic plastic tube					
VS-25ETS08STRR-M3	800	800	13" diameter reel					
VS-25ETS08STRL-M3	800	800	13" diameter reel					
VS-25ETS10S-M3	50	1000	Antistatic plastic tube					
VS-25ETS10STRR-M3	800	800	13" diameter reel					
VS-25ETS10STRL-M3	800	800	13" diameter reel					
VS-25ETS12S-M3	50	1000	Antistatic plastic tube					
VS-25ETS12STRR-M3	800	800	13" diameter reel					
VS-25ETS12STRL-M3	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?96164</u>				
Part marking information	www.vishay.com/doc?95444			
Packaging information	www.vishay.com/doc?96424			

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D²PAK

DIMENSIONS in millimeters and inches



ota	ted	90	°C
<u>S</u>	cale	<u>ə:</u> 8	:1

SYMBOL	MILLIM	ETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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1

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